LDO Voltage Regulator

500 mA

These linear low drop voltage regulators provide up to 500 mA over a user-adjustable output range of 1.25 V to 5.0 V, or at a fixed output voltage of 1.5 V, 3.3 V or 5.0 V, with typical output voltage accuracy better than 3%. An internal PNP pass transistor permits low dropout voltage and operation at full load current at the minimum input voltage. NCV versions are qualified for demanding automotive applications that require extended temperature operation and site and change control. NCP5500 and NCV5500 versions include an Enable/Shutdown function and are available in a DPAK 5 and SOIC 8 packages. NCP5501 and NCV5501 versions are available in DPAK 3 for applications that do not require logical on/off control.

This regulator family is ideal for applications that require a broad input voltage range, and low dropout performance up to 500 mA load using low cost ceramic capacitors. Integral protection features include short circuit current and thermal shutdown.

Features

- Output Current up to 500 mA
- 2.9% Output Voltage Accuracy
- Low Dropout Voltage (230 mV at 500 mA)
- Enable Control Pin (NCP5500 / NCV5500)
- Reverse Bias Protection
- Short Circuit Protection
- Thermal Shutdown
- Wide Operating Temperature Range NCV5500 / NCV5501; -40°C to +125°C Ambient Temperature NCP5500 / NCP5501; -40°C to +85°C Ambient Temperature
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- Stable with Low Cost Ceramic Capacitors
- These are Pb-Free Devices

Typical Applications

- Automotive
- Industrial and Consumer
- Post SMPS Regulation
- Point of Use Regulation



ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS



Pin 1. EN

DPAK 5 **CENTER LEAD CROP** CASE 175AA



2. V_{in} TAB, 3. GND 4. Vout 5. NC/ADJ



DPAK 3 SINGLE GAUGE **CASE 369C**



Pin 1. V_{in} TAB, 2. GND 3. V_{out}

= P (NCP), V (NCV) 5500/1 = Device Code = Output Voltage L = 1.5 VT = 3.3 VU = 5.0 VW = Adjustable = Assembly Location

L = Wafer Lot Υ = Year WW = Work Week = Pb-Free Package



SOIC-8 **CASE 751**

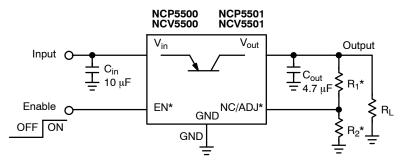


Pin 1. V_{in} x = Output Voltage, NCP/NCV 2. GND A = Adjustable, NCV 3. GND B = Adjustable, NCP 4. Vout A = Assembly Location 5. NC/ADJ = Wafer Lot 6. GND Υ

= Year 7. GND W = Work Week 8. EN = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.



*Applicable to NCP5500/NCV5500 only.

Figure 1. Typical Application Circuit

PIN FUNCTION DESCRIPTIONS

DPAK 3	DPAK 5	SOIC-8	Pin	
Pin No.	Pin No.	Pin No.	Name	Description
-	1	8	EN	Enable. This pin allows for on/off control of the regulator. High level turns on the output. To disable the device, connect to ground. If this function is not in use, connect to $V_{\rm in}$.
1	2	1	V _{in}	Positive power supply input voltage.
2, Tab	3, Tab	2, 3, 6, 7	GND	Ground. This pin is internally connected to the Tab heat sink.
3	4	4	V _{out}	Regulated output voltage.
-	5	5	NC/ADJ	No connection (Fixed output versions). Voltage-adjust input (Adjustable output version). Use an external voltage divider to set the output voltage over a range of 1.25 V to 5.0 V.

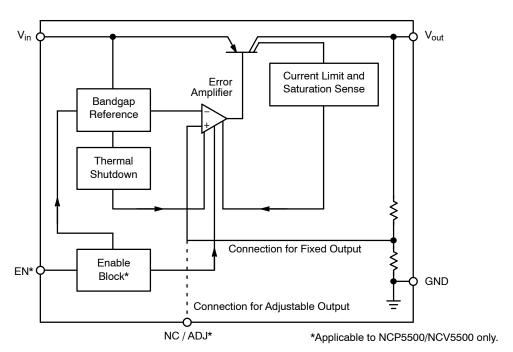


Figure 2. Block Diagram

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Min	Max	Unit
Input Voltage (Note 1)	V _{in}	-0.3 (Note 2)	+18	V
Output, Enable Voltage	V _{out} , EN	-0.3	+16 or V _{in} + 0.3 (Notes 2 and 5)	V
Maximum Junction Temperature	TJ	-	150	°C
Storage Temperature	T _{Stg}	-55	+150	°C
Moisture Sensitivity Level All Packages	MSL	1		-
Lead Temperature Soldering Reflow (SMD Styles Only), Pb-Free Versions (Note 3)	T _{sld}		265 Peak	°C
ESD Capability, Human Body Model (Note 4)	ESD _{HBM}	4000	-	V
ESD Capability, Machine Model (Note 4)	ESD _{MM}	200	-	V
ESD Capability, Charged Device Model (Note 4)	ESD _{CDM}	1000	-	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- *Latchup Current Maximum Rating: ≤ 100 mA per JEDEC standard: JESD78.

- Refer to Electrical Characteristics and Application Information for Safe Operating Area.
 Reverse bias protection feature valid only if V_{out} V_{in} ≤ 7 V.
 Pb-Free, 60 sec -150 sec above 217°C, 40 sec max at peak temperature
 This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
 - ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)
 - ESD Charged Device Model tested per EIA/JES D22/C101, Field Induced Charge Model
- 5. Maximum = +16 V or ($V_{in} + 0.3$ V), whichever is lower.

THERMAL CHARACTERISTICS

Rating	Symbol	Min	Max	Unit
Package Dissipation	P_{D}		Internally Limited	W
Thermal Characteristics, DPAK 3 and DPAK 5 (Note 1) Thermal Resistance, Junction-to-Air (Note 6) Thermal Resistance, Junction-to-Case	R _{θJA} R _{θJC}		60 5.2	°C/W
Thermal Characteristics, SOIC-8 (Note 1) Thermal Resistance, Junction-to-Air (Note 6) Thermal Reference, Junction-to-Lead	R _{θJA} R _{ΨJL}		80 22	°C/W

^{6.} As measured using a copper heat spreading area of 650 mm², 1 oz copper thickness.

OPERATING RANGES

Rating	Symbol	Min	Max	Unit
Operating Input Voltage (Note 1)	V _{in}	V _{out} + V _{DO} , 2.5 V (Note 7)	16	V
Adjustable Output Voltage Range (Adjustable Version Only)	V _{out}	1.25	5.0	V
Operating Ambient Temperature Range NCP5500, NCP5501 NCV5500, NCV5501	T _A	-40 -40	85 125	°C

^{7.} Minimum V_{in} = 2.5 V or (V_{out} + V_{DO}), whichever is higher.

ELECTRICAL CHARACTERISTICS V_{in} = 2.5 V or V_{out} + 1.0 V (whichever is higher), C_{in} = 10 μ F, C_{out} = 4.7 μ F, for typical values T_A = 25° C, for min/max values $T_A = -40^{\circ}$ C to 85° C (NCP Version), $T_A = -40^{\circ}$ C to 125° C (NCV Version) unless otherwise noted (Note 13).

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
ОИТРИТ						
Output Voltage (Note 14) 5 V Regulator 3.3 V Regulator 1.5 V Regulator ADJ Regulator	V _{out}	T _A = 25°C, I _{out} = 50 mA		V _{NOM} ±2.9%		V V V
Output Voltage (Note 8) 5 V Regulator 3.3 V Regulator 1.5 V Regulator ADJ Regulator	V _{out}	1.0 mA < I _{out} < 500 mA	(-4.9%) 4.755 3.138 1.427 1.189	V _{NOM} 5.0 3.3 1.5 1.25	(+4.9%) 5.245 3.462 1.574 1.311	V V V
Line Regulation	REG _{LINE}	$I_{out} = 50 \text{ mA}$ 2.5 V or $(V_{out} + 1.0 \text{ V}) < V_{in} < 16 \text{ V}$	-1.0	0.1	1.0	%
Load Regulation	REG_LOAD	1.0 mA < I _{out} < 500 mA	-1.0	0.35	1.0	%
Dropout Voltage (Note 9) 5.0 V Version 3.3 V Version 1.5 V Version (Note 10) Adjustable Version (Note 11)	V _{DO}	$\begin{split} I_{out} &= 1.0 \text{ mA}, \Delta V_{out} = -2\% \\ I_{out} &= 500 \text{ mA}, \Delta V_{out} = -2\% \\ I_{out} &= 1.0 \text{ mA}, \Delta V_{out} = -2\% \\ I_{out} &= 500 \text{ mA}, \Delta V_{out} = -2\% \\ I_{out} &= 500 \text{ mA}, \Delta V_{out} = -2\% \\ I_{out} &= 1.0 \text{ mA}, \Delta V_{out} = -2\% \\ I_{out} &= 500 \text{ mA}, \Delta V_{out} = -2\% \\ I_{out} &= 1.0 \text{ mA}, \Delta V_{out} = -2\% \\ I_{out} &= 500 \text{ mA}, \Delta V_{out} = -2\% \end{split}$	-	5 230 5 230 - - 5 230	90 700 90 700 1073 1073 90 700	mV
Ground Current	I _{GND}	I _{out} = 100 μA I _{out} = 500 mA		300 10	500 20	μA mA
Disable Current in Shutdown (NCP5500, NCV5500)	I _{SD}	Adjustable and 1.5 V versions All other versions		30 40	50 50	μΑ
Current Limit	I _{out(LIM)}	V _{out} = 90% of V _{out(nom)}	500	700	900	mA
Ripple Rejection Ratio (Notes 9 & 14)	RR	120 Hz I _{out} = 100 mA, 1 kHz 10 kHz	- - -	75 75 70	- - -	dB
Output Noise Voltage (Notes 12 & 14)	V _n	f = 10 Hz to 100 kHz, V _{in} = 2.5 V V _{out} = 1.25 V, I _{out} = 1.0 mA f = 10 Hz to 100 kHz, V _{in} = 2.5 V V _{out} = 1.25 V, I _{out} = 100 mA		18 35		μVrms
ENABLE (NCP5500, NCV5500 Only)	1				I	1
Enable Voltage	$V_{ENoff} \ V_{ENon}$	OFF (shutdown) State ON (enabled) State	2.0		0.4	V
Enable Pin Bias Current	I _{EN}	$V_{EN} = V_{in}$, $I_{out} = 1.0 \text{ mA}$		-	1.0	μΑ
ADJUST						
Adjust Pin Current (Note 14)	I_{ADJ}	$V_{EN} = V_{in}$, $V_{ADJ} = 1.25 \text{ V}$, $V_{out} = 1.25 \text{ V}$		-	60	nA
THERMAL SHUTDOWN						
Thermal Shutdown Temperature (Note 14)	TSD	I _{out} = 100 μA	150	-	210	°C

^{8.} Deviation from nominal. For adjustable versions, Pin ADJ connected to Vout.

^{9.} See Typical Characteristics section for additional information.

 $^{10.\,}V_{DO}$ is constrained by the minimum input voltage of 2.5 V.

^{11.} V_{out} is set by external resistor divider to 5 V.
12. V_n for other fixed voltage versions, as well as adjustable versions set to other output voltages, can be calculated from the following formula:

V_n | Or other index voltage versions, as well as adjustable versions set to other output voltages, can be calculated from the following formula:
 V_n = V_{n(x)} * V_{out} / 1.25, where V_{n(x)} is the typical value from the table above.
 13. Performance guaranteed over specified operating conditions by design, guard banded test limits, and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

^{14.} Values are based on design and/or characterization.

TYPICAL CHARACTERISTICS

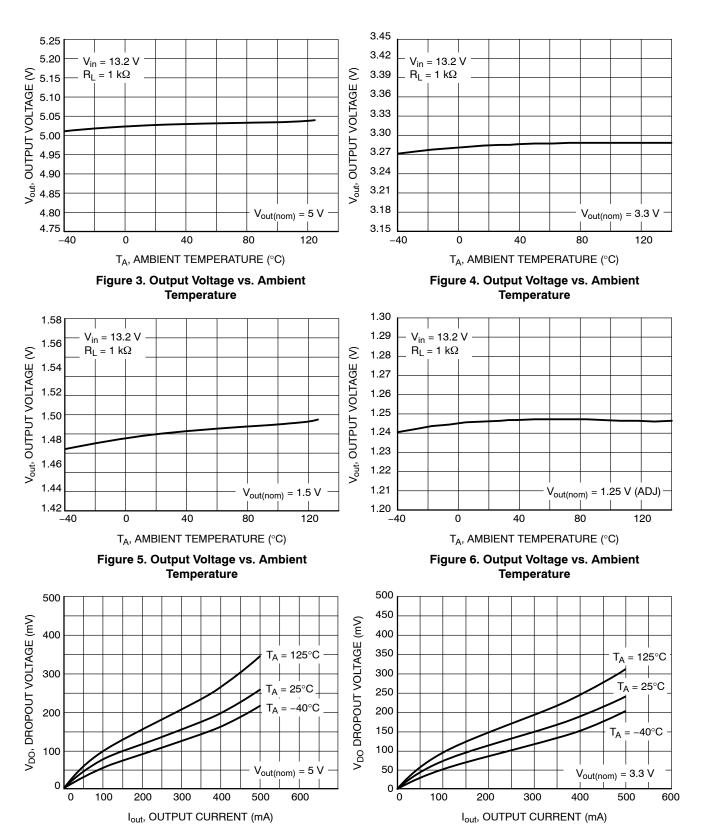


Figure 7. Dropout Voltage vs. Output Current Figure 8. Dropout Voltage vs. Output Current

TYPICAL CHARACTERISTICS

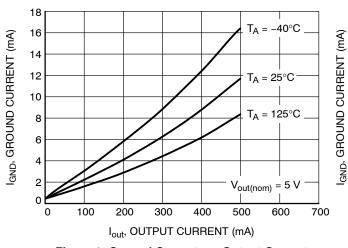


Figure 9. Ground Current vs. Output Current

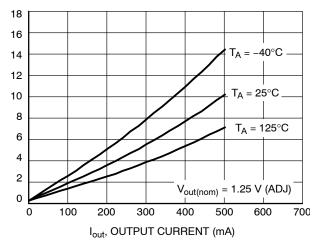


Figure 10. Ground Current vs. Output Current

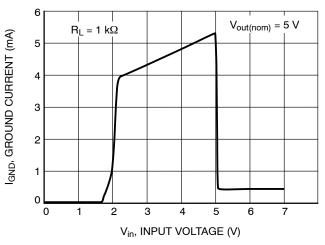


Figure 11. Ground Current vs. Input Voltage

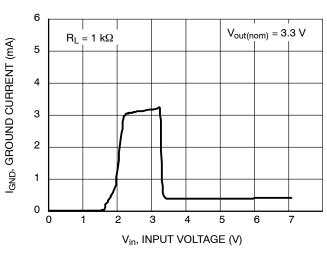


Figure 12. Ground Current vs. Input Voltage

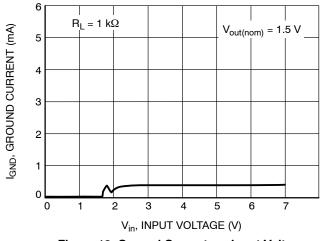


Figure 13. Ground Current vs. Input Voltage

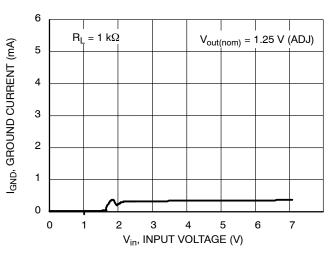
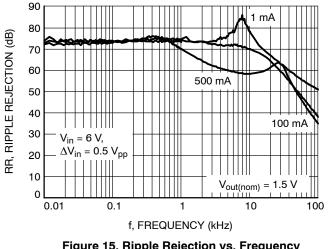


Figure 14. Ground Current vs. Input Voltage

TYPICAL CHARACTERISTICS

RR, RIPPLE REJECTION (dB)

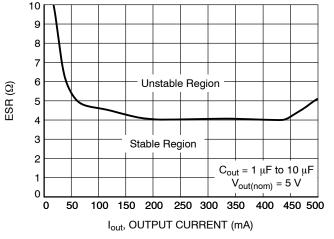
ESR (Q)



90 80 1 mA 100 mA 70 60 500 mA 50 40 30 $V_{in} = 6 V$, $\Delta V_{in} = 0.5 V_{pp}$ 20 10 $V_{out(nom)}$ 0 0.01 0.1 10 100 f, FREQUENCY (kHz)

Figure 15. Ripple Rejection vs. Frequency

Figure 16. Ripple Rejection vs. Frequency



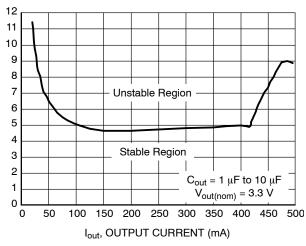
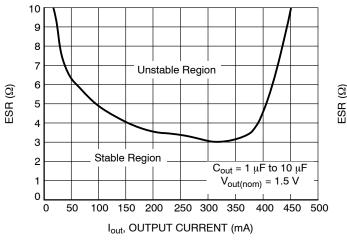


Figure 17. Output Capacitor ESR Stability vs. **Output Current**

Figure 18. Output Capacitor ESR Stability vs. **Output Current**



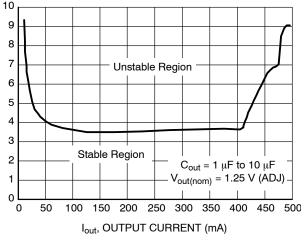


Figure 19. Output Capacitor ESR Stability vs. **Output Current**

Figure 20. Output Capacitor ESR Stability vs. **Output Current**

NOTE: Typical characteristics were measured with the same conditions as electrical characteristics, unless otherwise noted.

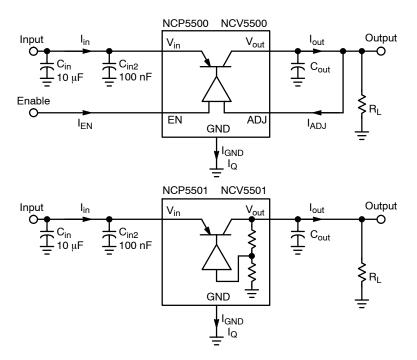


Figure 21. Measuring Circuits

Circuit Description

The NCP5500/NCP5501/NCV5500/NCV5501 are integrated linear regulators with a DC load current capability of 500 mA. The output voltage is regulated by a PNP pass transistor controlled by an error amplifier and band gap reference. The choice of a PNP pass element provides the lowest possible dropout voltage, particularly at reduced load currents. Pass transistor base drive current is controlled to prevent oversaturation. The regulator is internally protected by both current limit and thermal shutdown. Thermal shutdown occurs when the junction temperature exceeds 150°C. The NCV5500 includes an enable/shutdown pin to turn off the regulator to a low current drain standby state.

Regulator

The error amplifier compares the reference voltage to a sample of the output voltage (V_{out}) and drives the base of a PNP series pass transistor via a buffer. The reference is a bandgap design for enhanced temperature stability. Saturation control of the PNP pass transistor is a function of the load current and input voltage. Oversaturation of the output power device is prevented, and quiescent current in the ground pin is minimized.

Regulator Stability Considerations

The input capacitor is necessary to stabilize the input impedance to reduce transient line influences. The output capacitor helps determine three main characteristics of a linear regulator: startup delay, load transient response and loop stability. The capacitor value and type should be based on cost, availability, size and temperature constraints. Refer to Typical Operating Characteristics for stability regions.

Enable Input (NCP5500, NCV5500)

The enable pin is used to turn the regulator on or off. By holding the pin at a voltage less than 0.4 V, the output of the regulator will be turned off to a minimal current drain state. When the voltage at the Enable pin is greater than 2.0 V, the output of the regulator will be enabled and rise to the regulated output voltage. The Enable pin may be connected directly to the input pin to provide a constant enable to the regulator.

Active Load Protection in Shutdown (NCP5500,

NCV5500)

When a linear regulator is disabled (shutdown), the output (load) voltage should be zero. However, stray PC board leakage paths, output capacitor dielectric absorption, and inductively coupled power sources can cause an undesirable regulator output voltage if load current is low or zero. The NCV5500 features a load protection network that is active only during Shutdown mode. This network switches in a shunt current path (~500 μA) from V_{out} to Ground. This feature also provides a controlled ("soft") discharge path for the output capacitor after a transition from Enable to Shutdown.

Calculating Resistors for the ADJ Versions

The adjustable version uses feedback resistors to adjust the output to the desired output voltage. With V_{out} connected to ADJ, the adjustable version will regulate at 1.25 V $\pm 4.9\%$ (1250 \pm 61.25 mV).

Output voltage formula with an external resistor divider:

$$V_{out} = \left(1.25 \text{ V} - \left[60\text{E} - 9 \cdot \frac{(R_1 \cdot R_2)}{(R_1 + R_2)}\right]\right) \cdot \left(\frac{(R_1 + R_2)}{R_2}\right)$$

Where

 R_1 = value of the divider resistor connected between V_{out} and ADJ.

 R_2 = value of the divider resistor connected between ADJ and GND.

The term "1.25 V" has a tolerance of $\pm 4.9\%$; the term "60E-9" can vary in the range 15E-9 to 60E-9.

For values of R_2 less than 15 K Ω , the term within brackets ([]) will evaluate to less than 1 mV and can be ignored. This simplifies the output voltage formula to:

 V_{out} = 1.25 V * ((R1 + R2) / R2)) with a tolerance of \pm 4.9%, which is the tolerance of the 1.25 V output when delivering up to 500 mA of output current.

DEFINITION OF TERMS

Dropout Voltage: The input-to-output voltage differential at which the circuit ceases to regulate against further reduction input voltage. Measured when the output voltage has dropped 2% relative to the value measured at nominal input voltage. Dropout voltage is dependent upon load current and junction temperature.

Input Voltage: The DC voltage applied to the input terminals with respect to ground.

Line Regulation: The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

Load Regulation: The change in output voltage for a change in load current at constant chip temperature. Pulse loading techniques are employed such that the average chip temperature is not significantly affected.

Quiescent and Ground Current: The quiescent current is the current which flows through the ground when the LDO operates without a load on its output: internal IC operation, bias, etc. When the LDO becomes loaded, this term is called the Ground current. It is actually the difference between the input current (measured through the LDO input pin) and the output current.

Ripple Rejection: The ratio of the peak-to-peak input ripple voltage to the peak-to-peak output ripple voltage.

Current Limit: Peak current that can be delivered to the output.

Calculating Power Dissipation

The maximum power dissipation for a single output regulator (Figure 21) is:

$$P_{D(max)} = \left[V_{in(max)} - V_{out(min)}\right] I_{out(max)} + V_{in(max)} I_{GND}$$
 (eq. 1)

Where

 $V_{in(max)}$ is the maximum input voltage,

V_{out(min)} is the minimum output voltage,

 $I_{out(max)}$ is the maximum output current for the application, I_{GND} is the ground current at $I_{out(max)}$.

Once the value of $P_{D(max)}$ is known, the maximum permissible value of $R_{\theta JA}$ can be calculated:

$$R_{\theta JA} = \frac{\left(150^{\circ}C - T_{A}\right)}{P_{D}}$$
 (eq. 2)

The value of $R_{\theta JA}$ can then be compared with those in the Thermal Characteristics table. Those packages with $R_{\theta JA}$ less than the calculated value in Equation 2 will keep the die temperature below 150°C.

In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heat sink will be required.

Heat Sinks

A heat sink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of $R_{\theta JA}$:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CS} + R_{\theta SA}$$
 (eq. 3)

where

 $R_{\theta JC}$ is the junction-to-case thermal resistance,

 $R_{\theta CS}$ is the case–to–heatsink thermal resistance,

 $R_{\theta SA}$ is the heatsink-to-ambient thermal resistance.

 $R_{\theta JC}$ appears in the Thermal Characteristics table. Like $R_{\theta JA}$, it too is a function of package type. $R_{\theta CS}$ and $R_{\theta SA}$ are functions of the package type, heat sink and the interface between them. These values appear in data sheets of heat sink manufacturers.

Thermal, mounting, and heat sink considerations are further discussed in ON Semiconductor Application Note AN1040/D.

ORDERING INFORMATION

Device	Nominal Output Voltage*	Package Marking	Package	Shipping [†]
NCP5500DT15RKG		P5500LG	DPAK 5 (Pb-Free)	2500 / Tape & Reel
NCV5500DT15RKG**]	V5500LG	DPAK 5 (Pb-Free)	2500 / Tape & Reel
NCP5501DT15RKG		P5501LG	DPAK 3 (Pb-Free)	2500 / Tape & Reel
NCV5501DT15RKG**	1.5	V5501LG	DPAK 3 (Pb-Free)	2500 / Tape & Reel
NCP5501DT15G		P5501LG	DPAK 3 (Pb-Free)	75 Units / Rail
NCV5501DT15G**		V5501LG	DPAK 3 (Pb-Free)	75 Units / Rail
NCP5500DT33RKG		P5500TG	DPAK 5 (Pb-Free)	2500 / Tape & Reel
NCV5500DT33RKG**		V5500TG	DPAK 5 (Pb-Free)	2500 / Tape & Reel
NCP5501DT33RKG	3.3	P5501TG	DPAK 3 (Pb-Free)	2500 / Tape & Reel
NCV5501DT33RKG**		V5501TG	DPAK 3 (Pb-Free)	2500 / Tape & Reel
NCP5501DT33G]	P5501TG	DPAK 3 (Pb-Free)	75 Units / Rail
NCV5501DT33G**]	V5501TG	DPAK 3 (Pb-Free)	75 Units / Rail
NCP5500DT50RKG		P5500UG	DPAK 5 (Pb-Free)	2500 / Tape & Reel
NCV5500DT50RKG**]	V5500UG	DPAK 5 (Pb-Free)	2500 / Tape & Reel
NCP5501DT50RKG		P5501UG	DPAK 3 (Pb-Free)	2500 / Tape & Reel
NCV5501DT50RKG**	5.0	V5501UG	DPAK 3 (Pb-Free)	2500 / Tape & Reel
NCP5501DT50G		P5501UG	DPAK 3 (Pb-Free)	75 Units / Rail
NCV5501DT50G**]	V5501UG	DPAK 3 (Pb-Free)	75 Units / Rail
NCP5500DTADJRKG		P5500WG	DPAK 5 (Pb-Free)	2500 / Tape & Reel
NCV5500DTADJRKG**	- Adjustable	V5500WG	DPAK 5 (Pb-Free)	2500 / Tape & Reel
NCP5500DADJR2G	Adjustable	5500B	SO-8 (Pb-Free)	2500 / Tape & Reel
NCV5500DADJR2G**	Adjustable	5500A	SO-8 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

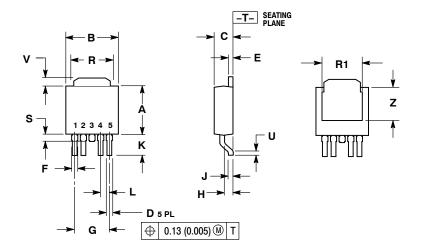
^{*}Contact ON Semiconductor for other fixed voltages.

^{**}NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable



DPAK-5, CENTER LEAD CROP CASE 175AA **ISSUE B**

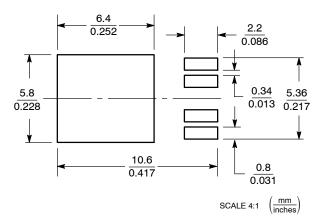
DATE 15 MAY 2014



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

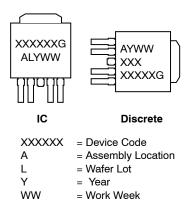
	INC	HES	MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.22
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.020	0.028	0.51	0.71
E	0.018	0.023	0.46	0.58
F	0.024	0.032	0.61	0.81
G	0.180	BSC	4.56 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.045	BSC	1.14 BSC	
R	0.170	0.190	4.32	4.83
R1	0.185	0.210	4.70	5.33
S	0.025	0.040	0.63	1.01
U	0.020		0.51	
٧	0.035	0.050	0.89	1.27
Z	0.155	0.170	3.93	4.32

RECOMMENDED SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAMS*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

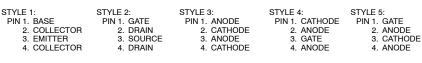
= Pb-Free Package

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DESCRIPTION:	DPAK-5 CENTER LEAD C	ROP	PAGE 1 OF 1

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DPAK (SINGLE GAUGE) CASE 369C ISSUE F SCALE 1:1 Α <-b3 В L3 Z ۩ **DETAIL A** Ш NOTE 7 C → **BOTTOM VIEW** h2 e SIDE VIEW ⊕ 0.005 (0.13) M C **TOP VIEW** Z H L2 GAUGE C SEATING PLANE

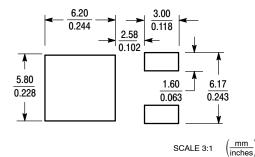


STYLE 6: STYLE 7: STYLE 8: STYLE 9: STYLE 10: PIN 1. MT1 2. MT2 PIN 1. GATE 2. COLLECTOR PIN 1. N/C 2. CATHODE PIN 1. ANODE 2. CATHODE PIN 1. CATHODE 2. ANODE 3. GATE 4. MT2 3. EMITTER 4. COLLECTOR 3. ANODE 4. CATHODE 3. RESISTOR ADJUST 4. CATHODE 3. CATHODE 4. ANODE

SOLDERING FOOTPRINT*

Α1

DETAIL A ROTATED 90° CW



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 21 JUL 2015

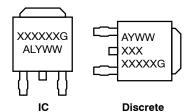
NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
- 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-
- MENSIONS b3, L3 and Z.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
 5. DIMENSIONS D AND E ARE DETERMINED AT THE
- OUTERMOST EXTREMES OF THE PLASTIC BODY.

 6. DATUMS A AND B ARE DETERMINED AT DATUM
- 7. OPTIONAL MOLD FEATURE.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
Е	0.250	0.265	6.35	6.73
е	0.090	BSC	2.29 BSC	
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114	REF	2.90	REF
L2	0.020 BSC		0.51	BSC
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	

GENERIC MARKING DIAGRAM*



XXXXXX = Device Code = Assembly Location Α L = Wafer Lot Υ = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	DPAK (SINGLE GAUGE)		PAGE 1 OF 1

BOTTOM VIEW

ALTERNATE CONSTRUCTIONS

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SOIC-8 NB CASE 751-07 **ISSUE AK**

DATE 16 FEB 2011



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27	7 BSC	0.050 BSC	
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location = Wafer Lot = Year = Work Week W

= Pb-Free Package

XXXXXX XXXXXX AYWW AYWW Ŧ \mathbb{H} Discrete **Discrete** (Pb-Free)

XXXXXX = Specific Device Code = Assembly Location Α = Year ww = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SOIC-8 NB CASE 751-07 ISSUE AK

DATE 16 FEB 2011

STYLE 1: PIN 1. EMITTER 2. COLLECTOR 3. COLLECTOR 4. EMITTER 5. EMITTER 6. BASE 7. BASE 8. EMITTER	STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 5. BASE, #2 6. EMITTER, #2 7. BASE, #1 8. EMITTER, #1	STYLE 3: PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1	STYLE 4: PIN 1. ANODE 2. ANODE 3. ANODE 4. ANODE 5. ANODE 6. ANODE 7. ANODE 8. COMMON CATHODE
STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN 4. DRAIN 5. GATE 6. GATE 7. SOURCE 8. SOURCE	STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE	STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd	STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE. #1
STYLE 9: PIN 1. EMITTER, COMMON 2. COLLECTOR, DIE #1 3. COLLECTOR, DIE #2 4. EMITTER, COMMON 5. EMITTER, COMMON 6. BASE, DIE #2 7. BASE, DIE #1 8. EMITTER, COMMON	STYLE 10: PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND 5. GROUND 6. BIAS 2 7. INPUT 8. GROUND	STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1	STYLE 12: PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 13: PIN 1. N.C. 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN	STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN	STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON	STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2 4. BASE, DIE #2 5. COLLECTOR, DIE #2 7. COLLECTOR, DIE #2 8. COLLECTOR, DIE #1 8. COLLECTOR, DIE #1
STYLE 17: PIN 1. VCC 2. V2OUT 3. V1OUT 4. TXE 5. RXE 6. VEE 7. GND 8. ACC	STYLE 18: PIN 1. ANODE 2. ANODE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE	STYLE 19: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1	STYLE 20: PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3. CATHODE 3 4. CATHODE 4 5. CATHODE 5 6. COMMON ANODE 7. COMMON ANODE 8. CATHODE 6	STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3. COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND	STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT	STYLE 24: PIN 1. BASE 2. EMITTER 3. COLLECTOR/ANODE 4. COLLECTOR/ANODE 5. CATHODE 6. CATHODE 7. COLLECTOR/ANODE 8. COLLECTOR/ANODE
STYLE 25: PIN 1. VIN 2. N/C 3. REXT 4. GND 5. IOUT 6. IOUT 7. IOUT 8. IOUT	STYLE 26: PIN 1. GND 2. dv/dt 3. ENABLE 4. ILIMIT 5. SOURCE 6. SOURCE 7. SOURCE 8. VCC	STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN	STYLE 28: PIN 1. SW TO GND 2. DASIC OFF 3. DASIC SW_DET 4. GND 5. V_MON 6. VBULK 7. VBULK 8. VIN
STYLE 29: PIN 1. BASE, DIE #1 2. EMITTER, #1 3. BASE, #2 4. EMITTER, #2 5. COLLECTOR, #2 6. COLLECTOR, #2 7. COLLECTOR, #1 8. COLLECTOR, #1	STYLE 30: PIN 1. DRAIN 1 2. DRAIN 1 3. GATE 2 4. SOURCE 2 5. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 8. GATE 1		

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